

100-Tap Digitally Programmable Potentiometer (DPP™)



FEATURES

- 100-position linear taper potentiometer
- Non-volatile EEPROM wiper storage
- 10 nA ultra-low standby current
- Single supply operation: 2.5 V 6.0 V
- Increment up/down serial interface
- Resistance values: 1 kΩ, 10 kΩ, 50 kΩ and 100 kΩ
- Available in PDIP, SOIC, TSSOP and MSOP packages

APPLICATIONS

- Automated product calibration
- Remote control adjustments
- Offset, gain and zero control
- Tamper-proof calibrations
- Contrast, brightness and volume controls
- Motor controls and feedback systems
- Programmable analog functions

For Ordering Information details, see page 12.

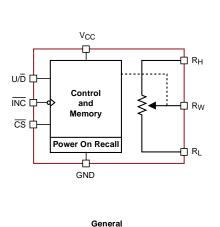
DESCRIPTION

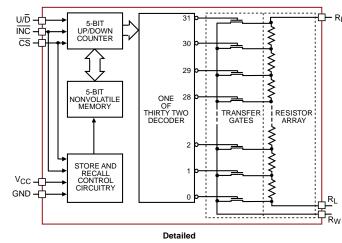
The CAT5113 is a single digitally programmable potentiometer (DPPTM) designed as a electronic replacement for mechanical potentiometers. Ideal for automated adjustments on high volume production lines, they are also well suited for applications where equipment requiring periodic adjustment is either difficult to access or located in a hazardous or remote environment.

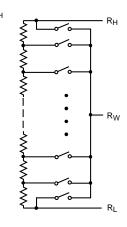
The CAT5113 contains a 100-tap series resistor array connected between two terminals $R_{\rm H}$ and $R_{\rm L}.$ An up/down counter and decoder that are controlled by three input pins, determines which tap is connected to the wiper, $R_{\rm W}.$ The wiper setting, stored in nonvolatile memory, is not lost when the device is powered down and is automatically reinstated when power is returned. The wiper can be adjusted to test new system values without affecting the stored setting. Wiper-control of the CAT5113 is accomplished with three input control pins, \bar{C} S, U/D, and \bar{I} NC. The \bar{I} NC input increments the wiper in the direction which is determined by the logic state of the U/D input. The \bar{C} S input is used to select the device and also store the wiper position prior to power down.

The digitally programmable potentiometer can be used as a three-terminal resistive divider or as a two-terminal variable resistor.

FUNCTIONAL DIAGRAM



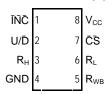




Electronic Potentiometer Implementation

PIN CONFIGURATION

PDIP 8-Lead (L) SOIC 8 Lead (V) MSOP 8 Lead (Z)



TSSOP 8 Lead (Y)

ČŠ	1	8	R_{L}
$V_{\text{CC}} \\$	2	7	R_{WB}
ĪÑŌ	3	6	GND
U/D̄	4	5	R_H

PIN DESCRIPTION

INC: Increment Control Input

The INC input moves the wiper in the up or down direction determined by the condition of the U/D input.

U/D: Up/Down Control Input

The U/D input controls the direction of the wiper movement. When in a high state and $\overline{\text{CS}}$ is low, any high-to-low transition on $\overline{\text{INC}}$ will cause the wiper to move one increment toward the R_H terminal. When in a low state and $\overline{\text{CS}}$ is low, any high-to-low transition on $\overline{\text{INC}}$ will cause the wiper to move one increment towards the R_L terminal.

R_H: High End Potentiometer Terminal

 $R_{\rm H}$ is the high end terminal of the potentiometer. It is not required that this terminal be connected to a potential greater than the $R_{\rm L}$ terminal. Voltage applied to the $R_{\rm H}$ terminal cannot exceed the supply voltage, $V_{\rm CC}$ or go below ground, GND.

Rw: Wiper Potentiometer Terminal

 $R_{\rm W}$ is the wiper terminal of the potentiometer. Its position on the resistor array is controlled by the control inputs, INC, U/D and CS. Voltage applied to the $R_{\rm W}$ terminal cannot exceed the supply voltage, $V_{\rm CC}$ or go below ground, GND.

R_L: Low End Potentiometer Terminal

 $R_{\rm L}$ is the low end terminal of the potentiometer. It is not required that this terminal be connected to a potential less than the $R_{\rm H}$ terminal. Voltage applied to the $R_{\rm L}$ terminal cannot exceed the supply voltage, $V_{\rm CC}$ or go below ground, GND. $R_{\rm L}$ and $R_{\rm H}$ are electrically interchangeable.

CS: Chip Select

The chip select input is used to activate the control input of the CAT5113 and is active low. When in a

PIN DESCRIPTIONS

Name	Function
ĪNĒ	Increment Control
U/D	Up/Down Control
R _H	Potentiometer High Terminal
GND	Ground
R _W	Wiper Terminal
R _L	Potentiometer Low Terminal
ČŠ	Chip Select
V _{cc}	Supply Voltage

high state, activity on the INC and U/D inputs will not affect or change the position of the wiper.

DEVICE OPERATION

The CAT5113 operates like a digitally controlled potentiometer with $R_{\rm H}$ and $R_{\rm L}$ equivalent to the high and low terminals and $R_{\rm W}$ equivalent to the mechanical potentiometer's wiper. There are 100 available tap positions including the resistor end points, $R_{\rm H}$ and $R_{\rm L}$. There are 99 resistor elements connected in series between the $R_{\rm H}$ and $R_{\rm L}$ terminals. The wiper terminal is connected to one of the 100 taps and controlled by three inputs, $IN\bar{C}$, U/\bar{D} and $C\bar{S}$. These inputs control a seven-bit up/down counter whose output is decoded to select the wiper position. The selected wiper position can be stored in non-volatile memory using the $IN\bar{C}$ and $C\bar{S}$ inputs.

With CS set LOW the CAT5113 is selected and will respond to the U/D and INC inputs. HIGH to LOW transitions on INC wil increment or decrement the wiper (depending on the state of the U/D input and seven-bit counter). The wiper, when at either fixed terminal, acts like its mechanical equivalent and does not move beyond the last position. The value of the counter is stored in nonvolatile memory whenever CS transitions HIGH while the INC input is also HIGH. When the CAT5113 is powered-down, the last stored wiper counter position is maintained in the nonvolatile memory. When power is restored, the contents of the memory are recalled and the counter is set to the value stored.

With INC set low, the CAT5113 may be de-selected and powered down without storing the current wiper position in nonvolatile memory. This allows the system to always power up to a preset value stored in nonvolatile memory.

OPERATION MODES

INC	£2	U/D	Operation
High to Low	Low	High	Wiper toward H
High to Low	Low	Low	Wiper toward L
High	Low to High	Х	Store Wiper Position
Low	Low to High	Х	No Store, Return to Standby
Х	High	Х	Standby

ABSOLUTE MAXIMUM RATINGS(1)

Parameters	Ratings	Units
Supply Voltage		
V _{CC} to GND	-0.5 to +7	V
Inputs		
CS to GND	-0.5 to V _{CC} +0.5	V
INC to GND	-0.5 to V _{CC} +0.5	V
U/D to GND	-0.5 to V _{CC} +0.5	V
H to GND	-0.5 to V _{CC} +0.5	V
L to GND	-0.5 to V _{CC} +0.5	V
W to GND	-0.5 to V _{CC} +0.5	V

Parameters	Ratings	Units
Operating Ambient Temperature		
Commercial ('C' or Blank suffix)	0 to 70	٥C
Industrial ('I' suffix)	-40 to +85	°C
Junction Temperature	+150	оС
Storage Temperature	-65 to 150	°C
Lead Soldering (10s max)	+300	°C

RELIABILITY CHARACTERISTICS

Symbol	Parameter	Test Method	Min	Тур	Max	Units
$V_{ZAP}^{(2)}$	ESD Susceptibility	MIL-STD-883, Test Method 3015	2000			V
I _{LTH} ^{(2) (3)}	Latch-Up	JEDEC Standard 17	100			mA
T_DR	Data Retention	MIL-STD-883, Test Method 1008	100			Years
N _{END}	Endurance	MIL-STD-883, Test Method 1003	1,000,000			Stores

DC ELECTRICAL CHARACTERISTICS

Vcc = +2.5 V to +6 V unless otherwise specified

Power Supply

Symbol	Parameter	Conditions	Min	Тур	Max	Units
V _{cc}	Operating Voltage Range		2.5	_	6.0	V
	Supply Current (Increment)	$V_{CC} = 6 \text{ V, f} = 1 \text{ MHz, I}_{W} = 0$	_	_	100	μΑ
I _{CC1}	Supply Current (Increment)	$V_{CC} = 6 \text{ V}, f = 250 \text{ kHz}, I_W = 0$	_	_	50	μΑ
	Supply Current (Write)	Programming, V _{CC} = 6 V	_	_	1000	μA
I _{CC2}	Supply Current (write)	V _{CC} = 3 V	_	_	500	μA
I _{SB1} ⁽³⁾	Supply Current (Standby)	\ddot{C} S = V _{CC} - 0.3 V U/D, \ddot{N} C = V _{CC} - 0.3 V or GND	_	0.01	1	μΑ

Notes:

- (1) Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions outside of those listed in the operational sections of this specification is not implied. Exposure to any absolute maximum rating for extended periods may affect device performance and reliability.
- (2) This parameter is tested initially and after a design or process change that affects the parameter.
- (3) Latch-up protection is provided for stresses up to 100 mA on address and data pins from -1 V to V_{CC} + 1 V
- (4) $I_W =$ source or sink
- (5) These parameters are periodically sampled and are not 100% tested.

Logic Inputs

Symbol	Parameter	Conditions	Min	Тур	Max	Units
I _{IH}	Input Leakage Current	$V_{IN} = V_{CC}$	-	_	10	μA
I _{IL}	Input Leakage Current	$V_{IN} = 0 V$	_	-	-10	μΑ
V_{IH2}	CMOS High Level Input Voltage	2.5 V ≤ V _{CC} ≤ 6 V	V _{CC} x 0.7	-	$V_{CC} + 0.3$	V
V _{IL2}	CMOS Low Level Input Voltage	2.5 V ≥ V _{CC} ≥ 0 V	-0.3	_	V _{CC} x 0.2	V

Potentiometer Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Units	
		-01 Device		1			
D	Potentiometer Resistance	-10 Device		10		kΩ	
R_{POT}	Poteritionneter Resistance	-50 Device		50		K22	
		-00 Device		100			
	Pot. Resistance Tolerance				±20	%	
V_{RH}	Voltage on R _H pin		0		V_{CC}	V	
V_{RL}	Voltage on R _L pin		0		V_{CC}	V	
	Resolution			1		%	
INL	Integral Linearity Error	I _W ≤ 2 μA		0.5	1	LSB	
DNL	Differential Linearity Error	I _W ≤ 2 μA		0.25	0.5	LSB	
R_{WI}	Wiper Resistance	$V_{CC} = 5 \text{ V}, I_W = 1 \text{ mA}$			400	Ω	
IXWI		$V_{CC} = 2.5 \text{ V}, I_{W} = 1 \text{ mA}$			1000	Ω	
I_W	Wiper Current	(1)	-4.4		4.4	mA	
TC_{RPOT}	TC of Pot Resistance			300		ppm/°C	
TC_{RATIO}	Ratiometric TC				20	ppm/ºC	
V_N	Noise	100 kHz / 1 kHz		8/24		nV/√Hz	
$C_H/C_L/C_W$	Potentiometer Capacitances			8/8/25		pF	
fc	Frequency Response	Passive Attenuator, 10 kΩ		1.7		MHz	

Notes:

(1) This parameter is not 100% tested.

AC CONDITIONS OF TEST

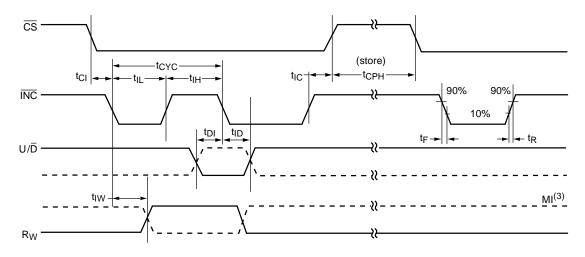
V _{CC} Range	2.5 V ≤ V _{CC} ≤ 6 V
Input Pulse Levels	$0.2V_{CC}$ to $0.7V_{CC}$
Input Rise and Fall Times	10 ns
Input Reference Levels	0.5V _{CC}

AC OPERATING CHARACTERISTICS

 V_{CC} = +2.5 V to +6.0 V, V_H = V_{CC} , V_L = 0 V, unless otherwise specified

Symbol	Parameter	Min	Typ ⁽¹⁾	Max	Units
t _{Cl}	CS to INC Setup	100	_	-	ns
t _{DI}	U/D to ĪNC Setup	50	_	_	ns
t _{ID}	U/D to ĪNC Hold	100	_	_	ns
t _{IL}	INC LOW Period	250	_	_	ns
t _{IH}	ĪNČ HIGH Period	250	_	_	ns
t _{IC}	ĪNC Inactive to CS Inactive	1	_	_	μs
t _{CPH}	CS Deselect Time (NO STORE)	100	_	_	ns
t _{CPH}	CS Deselect Time (STORE)	10	_	_	ms
t _{IW}	ĪNC to V _{OUT} Change	_	1	5	μs
t _{CYC}	ĪNČ Cycle Time	1	_	_	μs
$t_{R}, t_{F}^{(2)}$	ĪNČ Input Rise and Fall Time	_	_	500	μs
t _{PU} ⁽²⁾	Power-up to Wiper Stable	_	_	1	ms
t _{WR}	Store Cycle	_	5	10	ms

A.C. TIMING

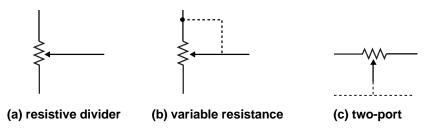


Notes:

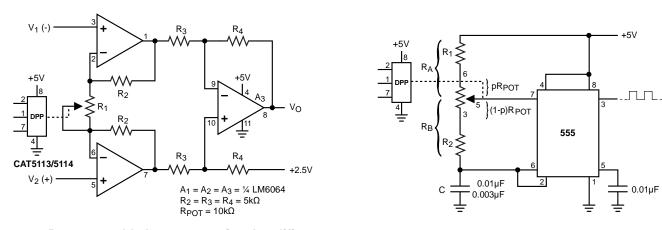
- (1) Typical values are for $T_A = 25^{\circ}C$ and nominal supply voltage.
- (2) This parameter is periodically sampled and not 100% tested.
- (3) MI in the A.C. Timing diagram refers to the minimum incremental change in the W output due to a change in the wiper position.

APPLICATIONS INFORMATION

Potentiometer Configuration

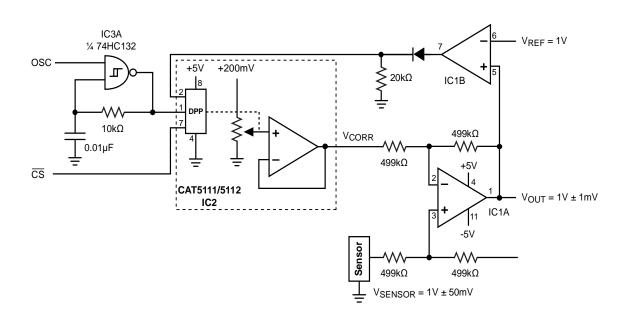


Applications



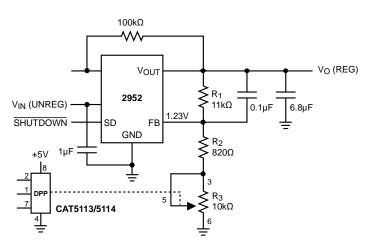
Programmable Instrumentation Amplifier

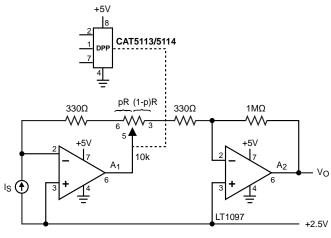
Programmable Sq. Wave Oscillator (555)



Sensor Auto Referencing Circuit

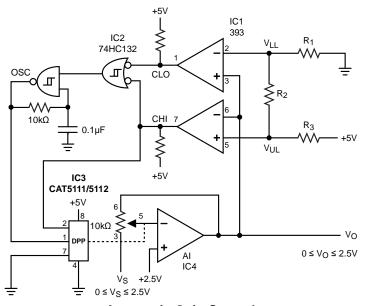
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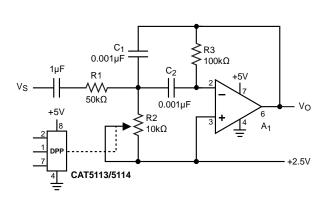




Programmable Voltage Regulator

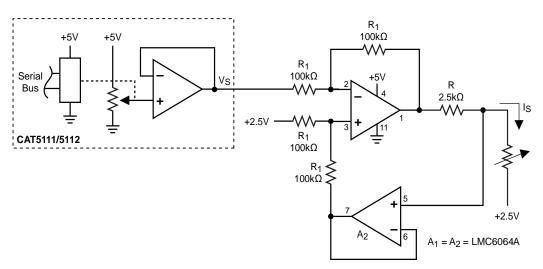
Programmable I to V Convertor





Automatic Gain Control

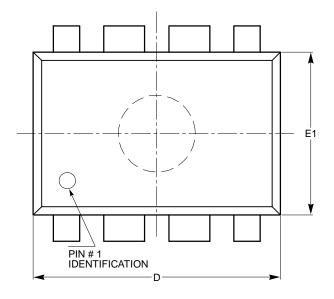
Programmable Bandpass Filter



Programmable Current Source/Sink

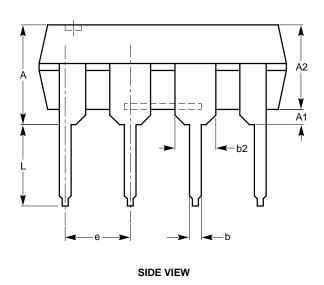
PACKAGE OUTLINE DRAWINGS

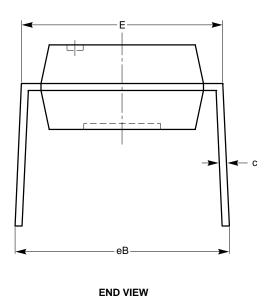
PDIP 8-Lead 300 mils (L)⁽¹⁾⁽²⁾



SYMBOL	MIN	NOM	MAX		
Α			5.33		
A1	0.38				
A2	2.92	3.30	4.95		
b	0.36	0.46	0.56		
b2	1.14	1.52	1.78		
С	0.20	0.25	0.36		
D	9.02	9.27	10.16		
Е	7.62	7.87	8.25		
е	2.54 BSC				
E1	6.10	6.35	7.11		
eB	7.87		10.92		
L	2.92	3.30	3.80		

TOP VIEW

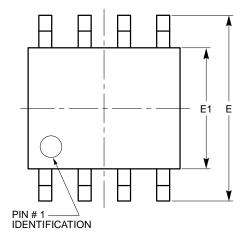




Notes:

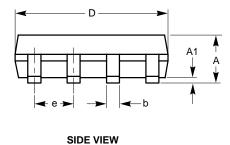
- (1) All dimensions are in millimeters.
- (2) Complies with JEDEC Standard MS-001.

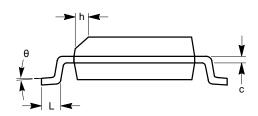
SOIC 8-Lead 150 mils (V) $^{(1)(2)}$



SYMBOL	MIN	NOM	MAX
А	1.35		1.75
A1	0.10		0.25
b	0.33		0.51
С	0.19		0.25
D	4.80		5.00
Е	5.80		6.20
E1	3.80		4.00
е		1.27 BSC	
h	0.25		0.50
L	0.40		1.27
θ	0°		8º

TOP VIEW



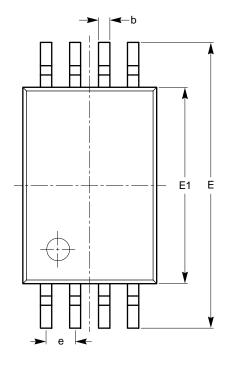


END VIEW

Notes:

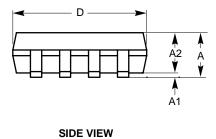
- (1) All dimensions are in millimeters. Angles in degrees.
- (2) Complies with JEDEC Specification MS-012.

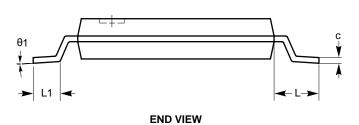
TSSOP 8-Lead 4.4 mm (Y) (1)(2)



SYMBOL	MIN	NOM	MAX
Α			1.20
A1	0.05		0.15
A2	0.80	0.90	1.05
b	0.19		0.30
С	0.09		0.20
D	2.90	3.00	3.10
Е	6.30	6.40	6.50
E1	4.30	4.40	4.50
е	0.65 BSC		
L	1.00 REF		
L1	0.50	0.60	0.75
θ1	0°		8°

TOP VIEW

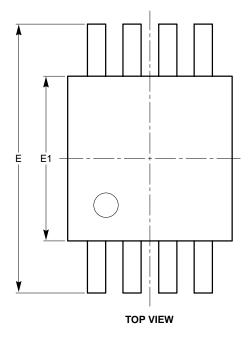




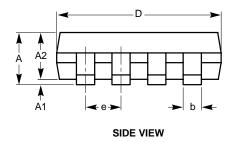
Notes

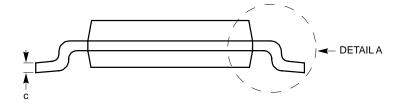
- (1) All dimensions are in millimeters.
- (2) Complies with JEDEC Standard MO-153

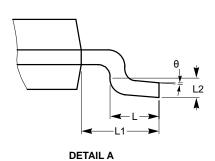
MSOP 8-Lead 3.0 x 3.0 mm (Z) $^{(1)(2)}$



SYMBOL	MIN	NOM	MAX
Α			1.10
A1	0.05	0.10	0.15
A2	0.75	0.85	0.95
b	0.22		0.38
С	0.13		0.23
D	2.90	3.00	3.10
Е	4.80	4.90	5.00
E1	2.90	3.00	3.10
е	0.65 BSC		
L	0.40	0.60	0.80
L1		0.95 REF	
L2	0.25 BSC		
θ	0°		6°



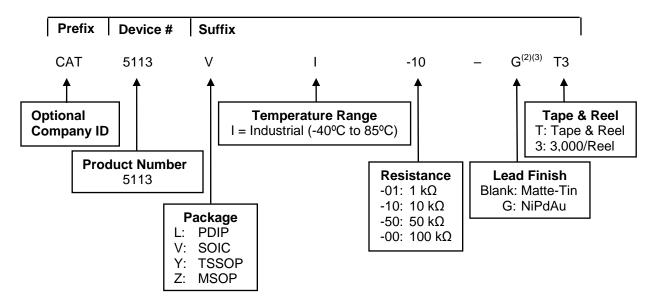




END VIEW

- All dimensions are in millimeters. Angles in degrees.
 Complies with JEDEC Specification MS-187.

EXAMPLE OF ORDERING INFORMATION



Notes:

- (1) All packages are RoHS-compliant (Lead-free, Halogen-free).
- (2) The standard lead finish is NiPdAu, except MSOP package is Matte-Tin.
- (3) Contact factory for Matte-Tin finish availability for PDIP, SOIC and TSSOP packages.
- (4) This device used in the above example is a CAT5113VI-10-GT3 (SOIC, Industrial Temperature, 10 kΩ, NiPdAu, Tape & Reel, 3,000/Reel).

ORDERING INFORMATION

Orderable Part Number	Resistance (kΩ)	Package-Pins	Lead Finish
CAT5113LI-01-G	1		
CAT5113LI-10-G	10	PDIP-8	NiPdAu
CAT5113LI-50-G	50	F DIF-0	NIFUAU
CAT5113LI-00-G	100		
CAT5113VI-01-GT3	1		
CAT5113VI-10-GT3	10	SOIC-8	NiPdAu
CAT5113VI-50-GT3	50	3010-6	MIFUAU
CAT5113VI-00-GT3	100		
CAT5113YI-01-GT3	1		
CAT5113YI-10-GT3	10	TSSOP-8	NiPdAu
CAT5113YI-50-GT3	50	1330F-6	MPuAu
CAT5113YI-00-GT3	100		
CAT5113ZI-01-T3	1		
CAT5113ZI-10-T3	10	MCODO	Motto Tip
CAT5113ZI-50-T3	50	MSOP-8	Matte-Tin
CAT5113ZI-00-T3	100		

REVISION HISTORY

Date	Rev.	Description
09-Oct-03	M	Revised Features Revised DC Electrical Characteristics
10-Mar-04	N	Updated Potentiometer Parameters
29-Mar-04	0	Changed Green Package marking for SOIC from W to V
02-Apr-04	Р	Add 1kΩ version to data sheet
08-Apr-04	Q	Eliminated data sheet designation Updated Tape and Reel specs in Ordering Information
25-Jan-05	R	Updated Potentiometer Parameters
22-Apr-06	S	Updated Example of Ordering Information
01-Jun-07	Т	Added Package Outline Added MD- in front of Document No.
15-Feb-08	U	Update Logic Inputs table Update Application Information (Sensor Auto Referencing Circuit and Programmable Current Source/Sink) Update Package Outline Drawings
27-Mar-08	V	Update Example of Ordering Information Delete MSOP in NiPdAu plated finish Add Top Mark Codes link
20-Nov-08	Х	Change logo and fine print to ON Semiconductor
10-Jul-09	Υ	Update Ordering Information table

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